



Pin Assignments

1A |

1Y

2A

2Y [

3A [

3Y

GND

General Purpose Logic

Power Down Signal Isolation

Wide array of products such as:

TV, DVD, DVR, set top box

Applications

74LV07A

Vcc

6A

6Y

5A

5Y

4A

4Y

HEX BUFFERS WITH OPEN DRAIN OUTPUTS

(Top View)

14

13

12

11

10

9

8

SO-14 / TSSOP-14

PCs, networking, notebooks, ultrabooks, netbooks

Computer peripherals, hard drives, CD/DVD ROM

0

2

3

4

5

6

Description

The 74LV07A provides provides six independent buffers with open drain outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

The gates perform the Boolean function:

 $\mathsf{Y} = \mathsf{A}$

Features

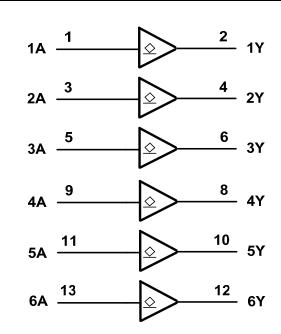
- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks 12mA at V_{CC} = 4.5V
- CMOS low power consumption
- IOFF Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
 - Latch-Up Exceeds 100mA per JESD 78, Class I
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click for Ordering Information



Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage



Logic Diagram

Function Table

Input	Output
А	Y
Н	Z
L	L

Symbol Parameter Rating Unit ESD HBM Human Body Model ESD Protection 2 kV ESD CDM Charged Device Model ESD Protection 1 kV ESD MM Machine Model ESD Protection 200 V -0.5 to +7.0 V V_{CC} Supply Voltage Range Input Voltage Range (Note 4) -0.5 to +7.0 V VI -20 mΑ Input Clamp Current $V_{I} < 0V$ Ι_{ΙΚ} Output Clamp Current Ιок $V_{\rm O} < 0V$ -50 mΑ Continuous Output Current -0.5V < Vo V_{CC} +0.5V - 25 mΑ I_{O} Continuous Current Through V_{CC} 50 mΑ Icc Continuous Current Through GND -50 mΑ I_{GND} -40 to +150 °C **Operating Junction Temperature** ΤJ -65 to +150 °C Storage Temperature T_{STG} Total Power Dissipation 500 PTOT mW

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	—	2.0	5.5	V
VI	Input Voltage	—	0	5.5	V
Vo	Output Voltage	—	0	5.5	V
		2.0V	—	50	μA
		2.3V to 2.7V	—	2	mA
I _{OL}	Low-Level Output Current	3.0V to 3.6V	—	6	mA
		4.5V to 5.5V	—	12	mA
		2.3V to 2.7V	—	200	
Δt/ΔV	Input Transition Rise or Fall Rate	3.0V to 3.6V	—	100	ns/V
		4.5V to 5.5V	—	20	
T _A	Operating Free-Air Temperature	_	-40	125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Deremeter	Test Conditions	Ň	T _A = -40°0	C to +85°C	T _A = -40°C	to +125°C	Unit
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
		—	2.0V	1.5	—	1.5	—	
	High-Level Input	—	2.3V to 2.7V	V _{CC} X 0.7	—	V _{CC} X 0.7	—	V
VIH	Voltage	—	3.0V to 3.6V	V _{CC} X 0.7	—	V _{CC} X 0.7	—	
		—	4.5V to 5.5V	V _{CC} X 0.7	—	V _{CC} X 0.7	—	—
		—	2.0V	—	0.5	_	0.5	
, Low-Level Input	_	2.3V to 2.7V	—	V _{CC} X 0.3	_	V _{CC} X 0.3	V	
VIL	Voltage	—	3.0V to 3.6V	—	V _{CC} X 0.3	—	V _{CC} X 0.3	
		—	4.5V to 5.5V	—	V _{CC} X 0.3	_	V _{CC} X 0.3	—
		I _{OL} = 50μA	2.0V to 5.5V	—	0.1	_	0.1	
Ň	Low-Level Output	I _{OL} = 2mA	2.3V	—	0.4	—	0.4	v
V _{OL}	Voltage	I _{OL} = 6mA	3.0V	—	0.44	_	0.44	
		I _{OL} = 12mA	4.5V	—	0.55	_	0.55	
I _{OFF}	Power Down Leakage Current	$V_{\rm I}$ or $V_{\rm O}$ = 0 to 5.5V	0V	—	5	—	5	μA
l _l	Input Current V _I =GND or 5.5V		0 to 5.5V	_	±1	—	±1	μA
Icc	Supply Current	$V_{I} = GND \text{ or } V_{CC}$ $I_{O}=0$	5.5V	_	20	_	20	μA



Switching Characteristics

$V_{CC} = 2.5V \pm$	0.2V									
Symbol	Parameter	Parameter Test Conditions		T _A = +25°C		-40°C to +85°C		-40°C to +125°C		Unit
Symbol	Falailletei	Test conditions	Min	Тур	Max	Min	Max	Min	Max	Onit
t _{PLZ}		Figure 1	-	6.6	10.4	1	13	1	13	ns
t _{PZL}	Propagation Delay A _N	C _L = 15pF	—	7.5	10.4	1	13	1	13	115
t _{PLZ}	to Y _N	Figure 1	—	11.1	15.2	1	18	1	18	20
t _{PZL}		C _L = 50pF	_	9.6	15.2	1	18	1	18	ns

V_{CC} = 3.3V ± 03 V

Symbol	Parameter	Test Conditions	Т	= +25°	С	-40°C to	o +85°C	-40°C to	o +125℃	Unit
Symbol	Farameter	Test Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLZ}		Figure 1	_	5	7.1	1	8.5	1	8.5	
t _{PZL}	Propagation Delay A _N	C _L = 15pF		5	7.1	1	8.5	1	8.5	ns
t _{PLZ}	to Y _N	Figure 1	_	8.2	10.6	1	12	1	12	20
t _{PZL}		C _L = 50pF		6.6	10.6	1	12	1	12	ns

$V_{CC} = 5.0V \pm 0.5V$

Symbol	Parameter	Test Conditions	Г	= +25°	C	-40°C to	o +85°C	-40°C to	+125°C	Unit
Symbol	Farameter	Test Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLZ}		Figure 1		3.8	5.5	1	6.5	1	6.5	ns
t _{PZL}	Propagation Delay A _N to	C _L = 15pF		3.4	5.5	1	6.5	1	6.5	115
t _{PLZ}	Y _N	Figure 1		5.7	7.5	1	8.5	1	8.5	
t _{PZL}		C _L = 50 pF	_	4.5	7.5	1	8.5	1	8.5	ns

Operating Characteristics

<u>T_A = +25°C</u>	^A = +25°C						
	Parameter	Test Conditions	V _{cc}	Тур	Unit		
<u> </u>	Power Dissipation	f = 10MHz	3.3V	2.9	рF		
C _{pd}	Capacitance per Gate	C _L = 50pF	5.0V	5.3	рг		

Noise Characteristics

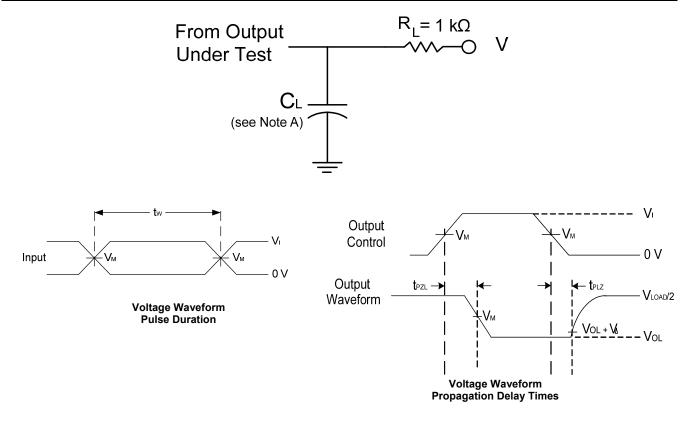
$V_{CC} = 3V, C_{L} =$	$/_{\rm CC}$ = 3V, C _L = 50pF, T _A = +25°C						
Symbol	Parameter	Min	Тур	Мах	Unit		
V _{OL(p)}	Quiet output, maximum dynamic V _{OL}	—	0.2	0.8	V		
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}	—	-0.1	-0.8	V		
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	_	3.1	_	V		
V _{IH(D)}	High Level dynamic input voltage	2.31	—	—	V		
V _{IL(D)}	Low Level dynamic input voltage	—	—	0.99	V		

Package Characteristics

Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	2.0 to 5.5V		3.3	10	pF



Parameter Measurement Information



A. Includes test lead and test apparatus capacitance. Notes:

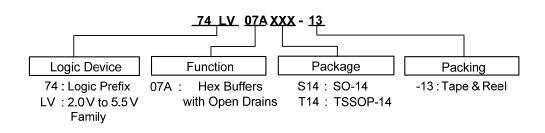
- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. The inputs are measured one at a time with one transition per measurement. D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD} .

- E. t_{PZL} is measured at $V_{M.}$ D. t_{PLZ} is measured at $V_{OL} + V_{\Delta}$ where $V_{\Delta} = 0.3V$.

Figure 1 Load Circuit and Voltage Waveforms



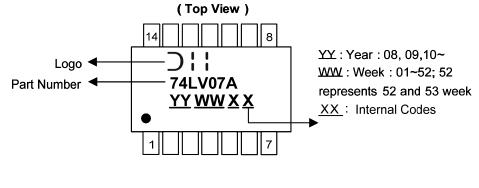
Ordering Information



	Device	Package Code	Packaging	13" Tape	and Reel			
	Device	Fackage Coue	(Note 6)	Quantity	Part Number Suffix			
	74LV07AS14-13	S14	SO-14	2500/Tape & Reel	-13			
	74LV07AT14-13 T14 TSSOP-14 2500/Tape & Reel -13							
Note:	ote: 6. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf							

Marking Information

(1) SO14, TSSOP14



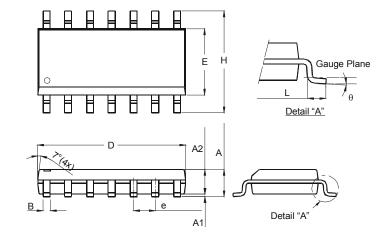
Part Number	Package
74LV07AS14	SO-14
74LV07AT14	TSSOP-14



Package Outline Dimensions (All Dimensions in mm)

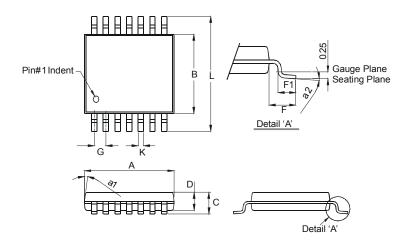
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



SO-14		
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
В	0.33	0.51
D	8.53	8.74
ш	3.80	3.99
e	1.27 Тур	
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14



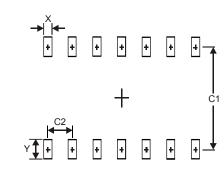
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С		1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
К	0.19	0.30
L	6.40 Тур	
All Dimensions in mm		



Suggested Pad Layout

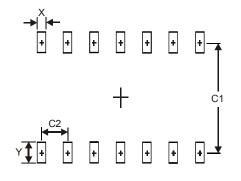
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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